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Vishay Semiconductors

ROHS

HALOGEN FREE

Hyperfast Rectifier, 30 A FRED Pt® G5



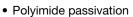
PRIMARY CHARACTERISTICS					
I _{F(AV)}	30 A				
V _R	1200 V				
V _F at I _F at 125 °C	2.1 V				
t _{rr}	26 ns				
T _J max.	175 °C				
Package	TO-247AD 2L				
Circuit configuration	Single				

FEATURES

- · Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off



• 175 °C maximum operating junction temperature



 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant. Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage	V_{RRM}		1200	V			
Average rectified forward current	I _{F(AV)}	T _C = 105 °C, D = 0.50	30				
Non-repetitive peak surge current	I _{FSM}	$T_C = 45$ °C, $t_p = 10$ ms, sine wave	210	Α			
Repetitive peak forward current	I _{FRM}	$T_C = 105 ^{\circ}\text{C}, D = 0.50, f = 20 \text{kHz}$	60				
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	1200	1	-		
Forward voltage	V _F	I _F = 30 A	-	2.6	3.15	V	
Forward voltage	v _F	I _F = 30 A, T _J = 125 °C	-	2.1	-		
Reverse leakage current	I _R	$V_R = V_R$ rated	-	-	50	50 500 μA	
heverse leakage current		T _J = 125 °C, V _R = V _R rated	-	-	500		
Junction capacitance	C _T	V _R = 200 V	-	17	-	pF	
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH	



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, dI_F/dt = 100$) A/μs, V _R = 30 V	-	26	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	100	-	ns	
		T _J = 125 °C		-	150	-		
Dook recovery ourrent		T _J = 25 °C	$I_F = 20 \text{ A}$	-	12	-	А	
Peak recovery current	I _{RRM}	T _J = 125 °C	$dI_F/dt = 600 \text{ A/}\mu\text{s}$ $V_R = 400 \text{ V}$	-	22	-		
Deviance receiver above	Q _{rr}	T _J = 25 °C		-	530	=.	nC	
Reverse recovery charge		T _J = 125 °C		=	1550	=.		
Dovorno rocover i timo	t _{rr}	T _J = 25 °C	$I_F = 30 \text{ A}$ $dI_F/dt = 1000 \text{ A/}\mu\text{s}$ $V_R = 800 \text{ V}$	-	80	-	ns	
Reverse recovery time		T _J = 125 °C		-	120	-		
Dools recovery as weent	I _{RRM}	T _J = 25 °C		-	22	-	Α	
Peak recovery current		T _J = 125 °C		-	37	-	A	
Reverse recovery charge	0	T _J = 25 °C		-	900	-	nC	
	Q_{rr}	T _J = 125 °C		-	2300	-		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Thermal resistance, junction-to-case	R _{thJC}		-	-	0.8	°C/W	
Weight			-	5.5	-	g	
			-	0.2	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Marking device		Case style: TO-247AD 2L	E5PX3012L				

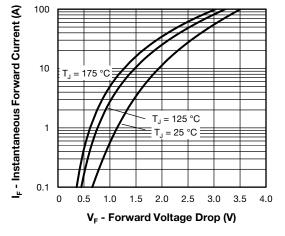


Fig. 1 - Typical Forward Voltage Drop Characteristics

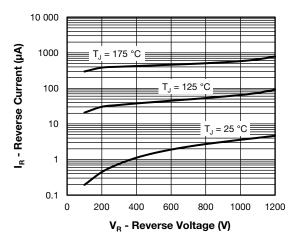


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

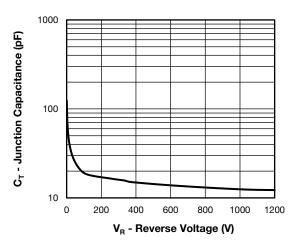


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

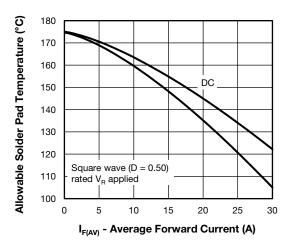


Fig. 4 - Maximum Allowable Case Temperature vs.
Average Forward Current

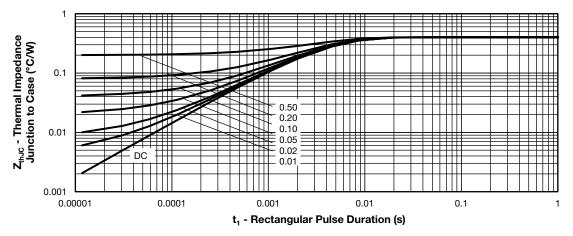


Fig. 5 - Thermal Impedance Z_{thJC} - Characteristics

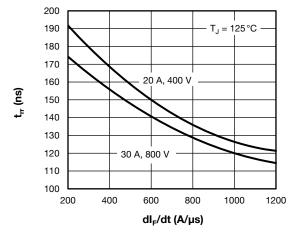


Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt

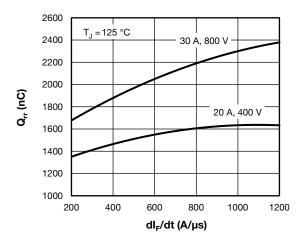


Fig. 7 - Typical Stored Charge vs. dl_F/dt

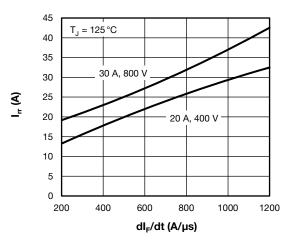


Fig. 8 - Typical Recovery Current vs. dl_F/dt

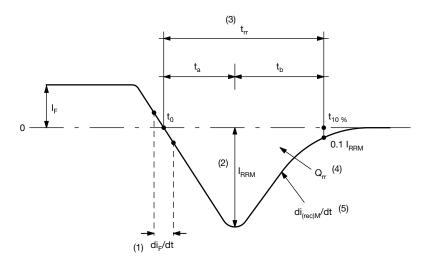


Fig. 9 - Reverse Recovery Waveform and Definitions

Notes

 $^{(1)}$ di_F/dt - rate of change of current through zero crossing

(2) I_{RRM} - peak reverse recovery current

 $^{(3)}$ t_{rr} - reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RRM}

 $^{(4)}$ Q_{rr} - area under curve defined by t_0 and $t_{10\,\%}$

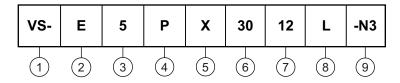
$$Q_{rr} = \int_{t_0}^{t_{10} \%} I(t) dt$$

 $^{(5)}$ $di_{(rec)}M/dt$ - peak rate of change of current during t_b portion of t_{rr}



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - E = single diode

5 = Fred generation 5

4 - Package:

P = TO-247 package

5 - X = hyperfast recovery

Current rating (30 = 30 A)

7 - Voltage rating (12 = 1200 V)

Package: L = long lead (TO-247AD)

9 - Environmental digit:

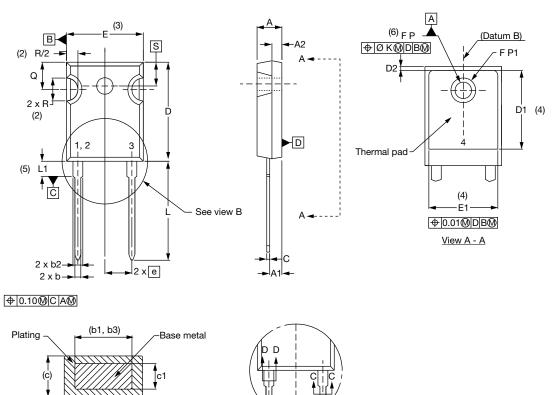
-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-E5PX3012L-N3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95536			
Part marking information	www.vishay.com/doc?95648			
Spice model	www.vishay.com/doc?96684			

TO-247AD 2L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INC	NOTES	
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4
D2	0.51	1.35	0.020	0.053	

Section C - C, D - D

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØK	0.2	0.254		0.010	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		
	•		•	•	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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